

PRELIMINARY TECHNICAL DATA

a

100 MHz – 2.7 GHz RF Gain Block

Preliminary Technical Data

AD8354

FEATURES

- Fixed gain of 20 dB
- Operational Frequency to 100 MHz to 2.7GHz
- Linear output power up to 4 dBm
- Input/Output internally matched to 50 ohms
- Temperature and power supply stable
- Noise figure 3.9 dB
- Power supply 3 V or 5 V

APPLICATIONS

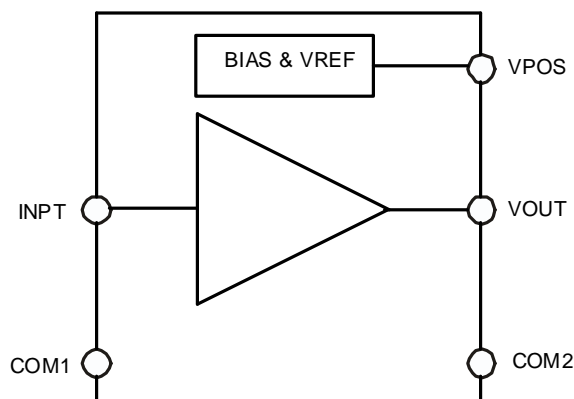
- VCO Buffers
- General Tx/Rx amplification
- Power amplifier predriver
- Low power antenna driver

PRODUCT DESCRIPTION

The AD8354 is a broadband, fixed-gain linear amplifier that operates at frequencies from 100 MHz up to 2.7 GHz. It is intended for use in a wide variety of wireless devices including cellular, broadband, CATV and LMDS/MMDS applications.

By taking advantage of Analog Devices' high performance complementary Si bipolar process, these gain blocks provide excellent stability over process, temperature and power supply. This amplifier is singled-ended and internally matched to 50 ohms with a return loss of greater than 10 dB over the full operating frequency range.

The AD8354 provides linear output power of nearly 4.3 dBm with 20 dB of gain at 900 MHz when biased at 3 V and an external RF choke is connected between the power supply and the output pin. The DC supply current is 24 mA. At 900 MHz, the output third order intercept (OIP3) is greater than +18 dBm, and is +13 dBm at 2.7 GHz.



The noise figure is 3.9 dB at 900 MHz. The reverse isolation (s_{12}) is -33 dB at 900 MHz.

The AD8354 can also operate with a 5 V power supply, in which case no external inductor is required. Under these conditions, the AD8354 delivers 4.4 dBm with 20 dB of gain at 900 MHz. The DC supply current is 26 mA. At 900 MHz, the OIP3 is greater than +19 dBm and is +14 dBm at 2.7 GHz. The noise figure is 3.9 dB at 900 MHz. The reverse isolation (s_{12}) is -33 dB.

The AD8354 is fabricated on Analog Devices' proprietary, high performance 25 GHz Si complementary bipolar IC process. The AD8354 is available in a chip scale package which utilizes an exposed paddle for excellent thermal impedance and low impedance electrical connection to ground. It operates over a -40 to +85 °C temperature range.

An evaluation board is available.

REV. PrE 9/10/01

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AD8354-SPECIFICATIONS

(Unless otherwise noted, $V_{POS} = 3V$, $T = 27^{\circ}C$, 100 nH external inductor
between VOUT and VPOS, $Z_o = 50 \Omega$)

Parameters	Conditions	Min	Typ	Max	Units
OVERALL FUNCTION					
Frequency Range		0.1		2.7	GHz
Gain	$f = 900 \text{ MHz}$		19.3		dB
	$f = 1.9 \text{ GHz}$		18.6		dB
	$f = 2.7 \text{ GHz}$		17		dB
Delta Gain	$f = 900 \text{ MHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dB
	$f = 1.9 \text{ GHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dB
	$f = 2.7 \text{ GHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dB
Gain Supply Sensitivity	$V_{POS} \pm 10\%$		0.6		dB/V
Reverse Isolation (s_{12})	$f = 900 \text{ MHz}$		-33		dB
	$f = 1.9 \text{ GHz}$		-33		dB
	$f = 2.7 \text{ GHz}$		-33.4		dB
RF INPUT INTERFACE					
Input Return Loss	Pin RFIN				
	$f = 900 \text{ MHz}$		23.2		dB
	$f = 1.9 \text{ GHz}$		25		dB
	$f = 2.7 \text{ GHz}$		19.5		dB
RF OUTPUT INTERFACE					
Output Compression Point	Pin VOUT				
	$f = 900 \text{ MHz}, 1 \text{ dB compression}$		4.3		dBm
	$f = 1.9 \text{ GHz}$		3.3		dBm
	$f = 2.7 \text{ GHz}$		2.3		dBm
	$f = 900 \text{ MHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dBm
	$f = 1.9 \text{ GHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dBm
	$f = 2.7 \text{ GHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dBm
Maximum Output Power	$f = 900 \text{ MHz}, \text{ saturated}$		6		dBm
Output Return Loss	$f = 900 \text{ MHz}$		24		dB
	$f = 1.9 \text{ GHz}$		17.2		dB
	$f = 2.7 \text{ GHz}$		14.7		dB
DISTORTION/ NOISE					
Output Third Order Intercept	$f = 900 \text{ MHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		19		dBm
	$f = 1.9 \text{ GHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		15.9		dBm
	$f = 2.7 \text{ GHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		13.8		dBm
Output Second Order Intercept	$f = 900 \text{ MHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		TBD		dBm
	$f = 1.9 \text{ GHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		TBD		dBm
	$f = 2.7 \text{ GHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		TBD		dBm
Noise Figure	$f = 900 \text{ MHz}$		3.9		dB
	$f = 1.9 \text{ GHz}$		TBD		dB
	$f = 2.7 \text{ GHz}$		TBD		dB
POWER INTERFACE					
Supply Voltage	Pin VPOS	2.7	3	3.3	V
Total Supply Current		23	24	27	mA
vs. Temperature	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$	22		27	mA
Supply Voltage Sensitivity		6	6.5	7.3	mA/V
Temperature Sensitivity	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$	40	41	44	$\mu A/^{\circ}C$

PRELIMINARY TECHNICAL DATA

AD8354-SPECIFICATIONS

(Unless otherwise noted, $V_{POS} = 5V$, $T=27^{\circ}C$, NO external inductor between VOUT and VPOS, $Z_0 = 50 \Omega$)

Parameters	Conditions	Min	Typ	Max	Units
OVERALL FUNCTION					
Frequency Range		0.1		2.7	GHz
Gain	$f = 900 \text{ MHz}$		19.4		dB
	$f = 1.9 \text{ GHz}$		18.5		dB
	$f = 2.7 \text{ GHz}$		17.2		dB/ $^{\circ}C$
Delta Gain	$f = 900 \text{ MHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dB
	$f = 1.9 \text{ GHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dB
	$f = 2.7 \text{ GHz}, -40^{\circ}C \leq T_A \leq 85^{\circ}C$				dB
Gain Temperature Sensitivity	$-40^{\circ}C$ to $85^{\circ}C$	-0.0063	-0.0065	-0.0081	dB/V
Gain Supply Sensitivity	$V_{POS} \pm 10\%$		0.54		dB
Reverse Isolation (S_{12})	$f = 900 \text{ MHz}$		-33.7		dB
	$f = 1.9 \text{ GHz}$		-37		dB
	$f = 2.7 \text{ GHz}$		-33		GHz
RF INPUT INTERFACE					
	Pin RFIN				
Input Return Loss	$f = 900 \text{ MHz}$		24.3		dB
	$f = 1.9 \text{ GHz}$		38		dB
	$f = 2.7 \text{ GHz}$		22		dB
RF OUTPUT INTERFACE					
	Pin VOUT				
Output 1 dB Compression	$f = 900 \text{ MHz}$		4.4		dBm
	$f = 1.9 \text{ GHz}$		4.1		dBm
	$f = 2.7 \text{ GHz}$		3.1		dBm
Maximum Output Power	$f = 900 \text{ MHz}$, saturated		7.0		dBm
Output Return Loss	$f = 900 \text{ MHz}$		27.3		dB
	$f = 1.9 \text{ GHz}$		38		dB
	$f = 2.7 \text{ GHz}$		19		dB
DISTORTION/ NOISE					
Output Third Order Intercept	$f = 900 \text{ MHz}, \Delta f = 50 \text{ MHz}, P_{IN} = -30 \text{ dBm}$		19.3		dBm
	$f = 1.9 \text{ GHz}, \Delta f = 50 \text{ MHz}, P_{IN} = -30 \text{ dBm}$		17		dBm
	$f = 2.7 \text{ GHz}, \Delta f = 50 \text{ MHz}, P_{IN} = -30 \text{ dBm}$		14.8		dBm
Output Second Order Intercept	$f = 900 \text{ MHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		TBD		dBm
	$f = 1.9 \text{ GHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		TBD		dBm
	$f = 2.7 \text{ GHz}, \Delta f = 1 \text{ MHz}, P_{IN} = -28 \text{ dBm}$		TBD		dBm
Noise Figure	$f = 900 \text{ MHz}$		3.9		dB
	$f = 1.9 \text{ GHz}$		TBD		dB
	$f = 2.7 \text{ GHz}$		5.2		dB
POWER INTERFACE					
	Pin VPOS				
Supply Voltage		4.5	5	5.5	V
Total Supply Current	$T_A = 27^{\circ}C$	24	26	28	mA
vs. Temperature	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$	23		28	mA
Supply Voltage Sensitivity		3.9	4.3	4.9	mA/V
Temperature Sensitivity	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$		28	36	$\mu A/^{\circ}C$

PRELIMINARY TECHNICAL DATA

AD8354

ABSOLUTE MAXIMUM RATINGS*

Supply Voltage VPOS..... .5.5V
 Input Power (re: 50 Ω).....+10 dBm
 Equivalent Voltage700 mVRMS
 Internal Power DissipationTBD
 θ_{JA} TBD $^{\circ}\text{C}/\text{W}$
 Maximum Junction Temperature+125 $^{\circ}\text{C}$
 Operating Temperature Range-40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$
 Storage Temperature Range-65 $^{\circ}\text{C}$ to +150 $^{\circ}\text{C}$
 Lead Temperature Range (Soldering 60 sec)..+300 $^{\circ}\text{C}$

*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

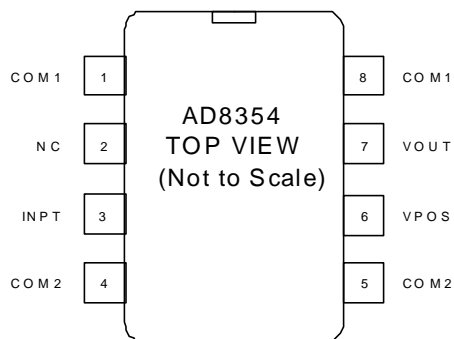
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8366 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy [>250 V HBM] electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



ORDERING GUIDE

Model	Temp. Range	Package Description
AD8354ACP	-30 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$	Tube, 8-Lead micro_SOIC
AD8354ACP-REEL7		7" Tape and Reel
AD8354-EVAL		Evaluation Board

PIN CONFIGURATION



Pin Function Descriptions

Pin	Name	Description	Equivalent Circuit
1,8	COM1	Device Common. Connect to low impedance ground.	Circuit A
2	INPT	RF Input Connection. Must be AC coupled.	
3,4	COM2	Device Common. Connect to low impedance ground.	Circuit A
5	VPOS	Positive Supply Voltage.	
6	NC	No Connection.	Circuit A
7	VOUT	RF Output Connection. Must be AC Coupled.	

PRELIMINARY TECHNICAL DATA

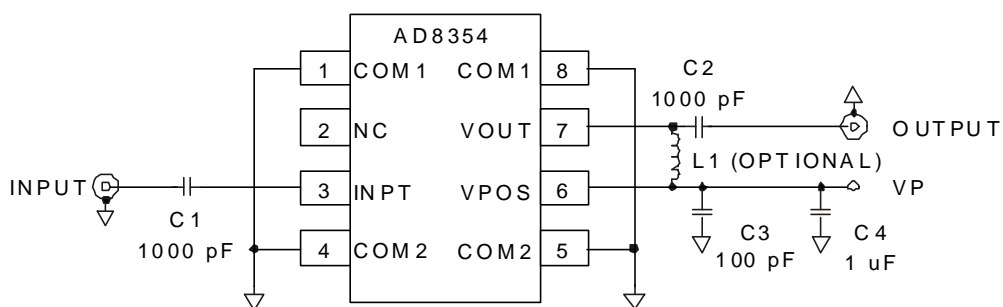


Figure 40. Evaluation Board Schematic

Evaluation Board

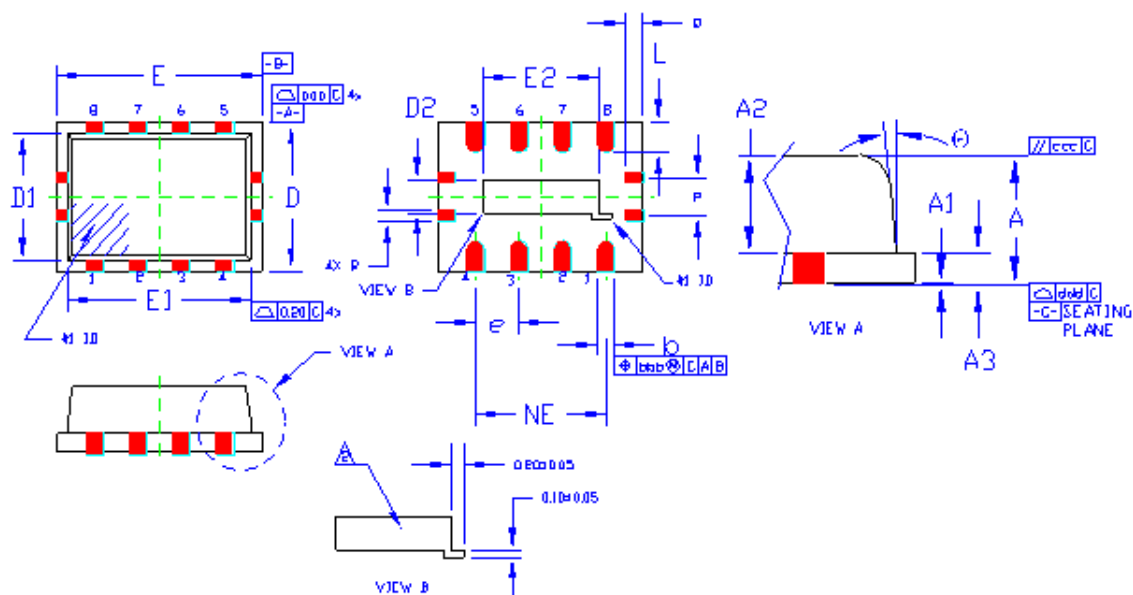
Figure 40. shows the schematic of the AD8354 evaluation board. Note that L1 is shown as an optional component, which is used to obtain maximum gain only when $V_p = 3$ V. The board is powered by a single supply in the range, +2.7 to +5.5V. The power supply is decoupled by a 0.47 μ F and a 100 pF capacitor .

Table II Evaluation Board Configuration Options

Component	Function	Default Value
C1, C2	AC coupling capacitors	1000 pF, 0603
C3	High frequency bypass capacitor	100 pF, 0603
C4	Low frequency bypass capacitor	0.047 μ F, 0603
L1	Optional RF choke, used to increase current through output stage when $V_p = 3$ V. Not recommended for use when $V_p = 5$ V.	100 nH, 0603

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SL LF-CSP (ANVIL) 2x3mm
Package Outline



Dim	Min.	Nom.	Max
D	1.75	2.00	2.25
D1	1.55	1.75	1.95
D2	0.30	0.45	0.60
E	2.75	3.00	3.25
E1	2.55	2.75	2.95
E2	1.59	1.74	1.89
L	0.30	0.40	0.55
NE	1.50 BSC.		
P	0.30	0.45	0.60
Q	0.15	0.25	0.50
R	0.13	0.17	0.23

Position Tolerance			
Dim	Min.	Nom.	Max
b	0.18	0.23	0.30
e	0.50 BSC		
aaa	0.25		
bbb	0.10		
ccc	0.10		
ddd	0.08		

Dim	Min.	Nom.	Max
A	0.80	0.90	1.00
A1	0.00	0.02	0.05
A2		0.65	0.75
A3	0.25 REF		
⊙	0°		12°
N	8		

NOTES:

1. Controlling Dimensions are in Millimeters(mm)

2. Paddle is copper plated with lead finish.